## MACOM PURE CARBIDE

**MAPC-A1519** 

Rev. V1

#### **Features**

- MACOM PURE CARBIDE® Amplifier Series
- Suitable for Linear & Saturated Applications
- CW & Pulsed Operation: 200 W Output Power
- Internally Pre-Matched
- 50 V Operation
- Compatible with MACOM Power Management Bias Controller/Sequencer MABC-11040

### **Applications**

Military Radio Communications, RADAR, Avionics, Digital Cellular Infrastructure, RF Energy, and Test Instrumentation.

### **Description**

The MAPC-A1519 is a high power GaN on Silicon Carbide HEMT D-mode amplifier suitable for 2.9 - 3.3 GHz frequency operation. The device supports both CW and pulsed operation with output power levels of at least 200 W (53.0 dBm) in an air cavity ceramic package.

### **Typical Performance:**

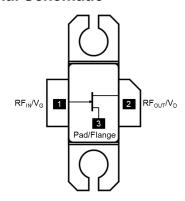
Measured under load-pull at 2.5 dB Compression, 100  $\mu$ s pulse width, 10% duty cycle.  $V_{DS}$  = 50 V,  $I_{DQ}$  = 300 mA,  $T_{C}$  = 25°C.

Frequency (GHz)	Output Power <sup>1</sup> (dBm)	Gain² (dB)	η <sub>D</sub> <sup>2</sup> (%)
2.9	54.2	16.7	68.2
3.1	54.0	16.3	65.8
3.3	53.8	16.5	69.2

- 1. Load impedance tuned for maximum output power.
- 2. Load impedance tuned for maximum drain efficiency.



#### **Functional Schematic**



## **Pin Configuration**

Pin#	Pin Name	Function
1	RF <sub>IN</sub> / V <sub>G</sub>	RF <sub>IN</sub> / Gate
2	RF <sub>OUT</sub> / V <sub>D</sub>	RF <sub>OUT</sub> / Drain
3	Flange <sup>3</sup>	Ground / Source

The flange on the package bottom must be connected to RF, DC and thermal ground.

#### **Ordering Information**

Part Number	Package
MAPC-A1519-AB000	Bulk Quantity
MAPC-A1519-ABTR1	Tape and Reel
MAPC-A1519-ABSB1	Sample Board

<sup>\*</sup> Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



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## RF Electrical Characteristics: $T_C = 25^{\circ}C$ , $V_{DS} = 50 \text{ V}$ , $I_{DQ} = 300 \text{ mA}$ Note: Performance in MACOM Evaluation Test Fixture, $50 \Omega$ system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	Pulsed <sup>4</sup> , 3.1 GHz	Gss	-	17.0		dB
Power Gain	Pulsed <sup>4</sup> , 3.1 GHz, 3 dB Gain Compression	G <sub>SAT</sub>	-	14.0	-	dB
Saturated Drain Efficiency	Pulsed <sup>4</sup> , 3.1 GHz, 3 dB Gain Compression	η <sub>SAT</sub>	-	60.8	-	%
Saturated Output Power	Pulsed <sup>4</sup> , 3.1 GHz, 3 dB Gain Compression	P <sub>SAT</sub>	-	53.6	-	dBm
Gain Variation (-25°C to +105°C)	Pulsed <sup>4</sup> , 3.1 GHz	ΔG	-	-0.02	1	dB/°C
Power Variation (-25°C to +105°C)	Pulsed <sup>4</sup> , 3.1 GHz	ΔP3dB	-	-0.01	ı	dB/°C
Ruggedness: Output Mismatch	All phase angles	Ψ VSWR = 10:1 No Device		Device D	Damage	

## RF Electrical Specifications: $T_A = 25^{\circ}C$ , $V_{DS} = 50 \text{ V}$ , $I_{DQ} = 300 \text{ mA}$ Note: Performance in MACOM Production Test Fixture, $50 \Omega$ system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Power Gain	Pulsed <sup>4</sup> , 3.1 GHz, 2.5 dB Gain Compression	$G_{SAT}$	14	15.4	-	dB
Saturated Drain Efficiency	Pulsed <sup>4</sup> , 3.1 GHz, 2.5 dB Gain Compression	η <sub>SAT</sub>	52	57.1	-	%
Saturated Output Power	Pulsed <sup>4</sup> , 3.1 GHz, 2.5 dB Gain Compression	P <sub>SAT</sub>	52	53.2	-	dBm

<sup>4.</sup> Pulse details: 100  $\mu s$  pulse width, 10% Duty Cycle.

## DC Electrical Characteristics T<sub>A</sub> = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	$V_{GS}$ = -8 V, $V_{DS}$ = 130 V	I <sub>DLK</sub>	-	-	26.8	mA
Gate-Source Leakage Current	V <sub>GS</sub> = -8 V, V <sub>DS</sub> = 0 V	I <sub>GLK</sub>	-	-	26.8	mA
Gate Threshold Voltage	V <sub>DS</sub> = 50 V, I <sub>D</sub> = 26.8 mA	V <sub>T</sub>	-	-3.0	-	٧
Gate Quiescent Voltage	V <sub>DS</sub> = 50 V, I <sub>D</sub> = 300 mA	$V_{GSQ}$	-	-2.6	-	٧
Maximum Drain Current	V <sub>DS</sub> = 7 V pulsed, pulse width 300 μs	I <sub>D, MAX</sub>	-	22.8	-	Α

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## Absolute Maximum Ratings 5,6,7,8,9

Parameter	Absolute Maximum		
Drain Source Voltage, V <sub>DS</sub>	130 V		
Gate Source Voltage, V <sub>GS</sub>	-10 to 3 V		
Gate Current, I <sub>G</sub>	26 mA		
Storage Temperature Range	-65°C to +150°C		
Case Operating Temperature Range	-40°C to +85°C		
Channel Operating Temperature Range, T <sub>CH</sub>	-40°C to +225°C		
Absolute Maximum Channel Temperature	+250°C		

Exceeding any one or combination of these limits may cause permanent damage to this device.

MACOM does not recommend sustained operation above maximum operating conditions.

## Thermal Characteristics<sup>10</sup>

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance using Finite Element Analysis	$V_{DS} = 50 \text{ V},$ $T_{C} = 85^{\circ}\text{C}, T_{CH} = 225^{\circ}\text{C}$	$R_{\theta}(FEA)$	1.50	°C/W
Thermal Resistance using Infrared Measurement of Die Surface Temperature	V <sub>DS</sub> = 50 V, T <sub>C</sub> = 85°C, T <sub>CH</sub> = 225°C	$R_{\theta}(IR)$	1.24	°C/W

<sup>10.</sup> Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement

#### **Handling Procedures**

Please observe the following precautions to avoid damage:

#### Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Operating at drain source voltage  $V_{DS} < 55 \text{ V}$  will ensure MTTF > TBD hours.

Operating at nominal conditions with  $T_{CH} \le 225^{\circ}\text{C}$  will ensure MTTF > TBD hours.

MTTF may be estimated by the expression MTTF (hours) = A  $e^{\frac{[B+C/(T+273)]}{2}}$  where T is the channel temperature in degrees Celsius, A = TBD, B = TBD, and C = TBD.



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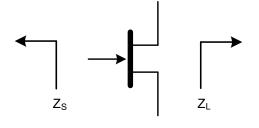
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## 50 V Pulsed<sup>4</sup> Load-Pull Performance **Reference Plane at Device Leads**

		Maximum Output Power					
			$V_{DS} = 50$	V, I <sub>DQ</sub> = 300 m/	A, T <sub>C</sub> = 25°C, F	P2.5dB	
Frequency (GHz)	Z <sub>SOURCE</sub> (Ω)	Z <sub>LOAD</sub> <sup>11</sup> (Ω)	Gain (dB)	P <sub>OUT</sub> (dBm)	P <sub>OUT</sub> (W)	η <sub>□</sub> (%)	AM/PM (°)
2.9	1.7 - j6.8	1.9 - j2.2	15.0	54.2	263	59.9	14.6
3.1	3.1 - j7.7	1.8 - j2.5	14.7	54.0	251	57.7	0.2
3.3	5.3 - j7.9	1.7 - j2.7	14.7	53.8	240	59.0	-22.6

		Maximum Drain Efficiency						
			V <sub>DS</sub> = 50 V, I <sub>DQ</sub> = 300 mA, T <sub>C</sub> = 25°C, P2.5dB					
Frequency (GHz)	Z <sub>source</sub> (Ω)	Z <sub>LOAD</sub> <sup>12</sup> (Ω)	Gain (dB)	P <sub>OUT</sub> (dBm)	P <sub>OUT</sub> (W)	η <sub>□</sub> (%)	AM/PM (°)	
2.9	1.4 - j6.9	1.4 - j1.0	16.7	52.8	191	68.2	2.2	
3.1	2.9 - j8.0	1.3 - j1.4	16.3	52.7	186	65.8	-11.2	
3.3	5.5 - j7.9	1.1 - j1.6	16.5	52.1	162	69.2	-34.7	

#### Impedance Reference



- $Z_{\text{SOURCE}}$  = Measured impedance presented to the input of the device at package reference plane.  $Z_{\text{LOAD}}$  = Measured impedance presented to the output of the
- device at package reference plane.
- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.

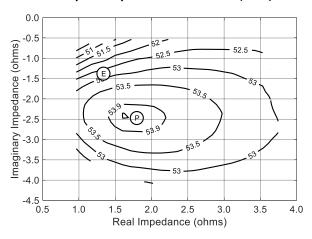
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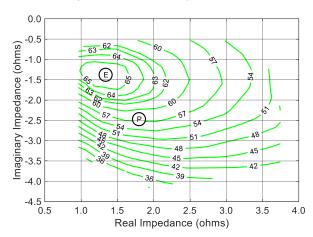
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## Pulsed<sup>4</sup> Load-Pull Performance @ 3.1 GHz

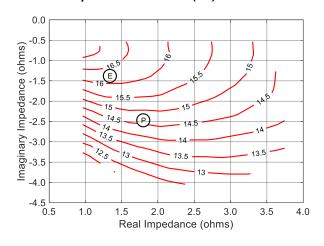
#### P2.5dB Loadpull Output Power Contours (dBm)



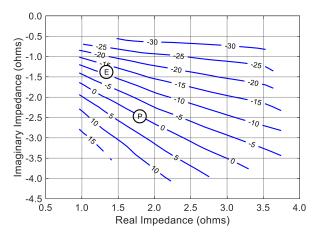
#### P2.5dB Loadpull Drain Efficiency Contours (%)



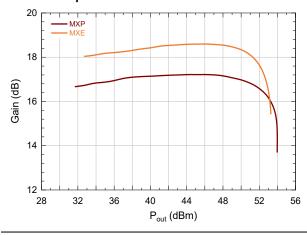
#### P2.5dB Loadpull Gain Contours (dB)



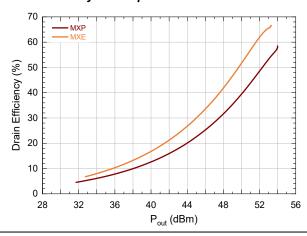
P2.5dB Loadpull AM/PM Contours (°)



#### Gain vs. Output Power



#### Drain Efficiency vs. Output Power

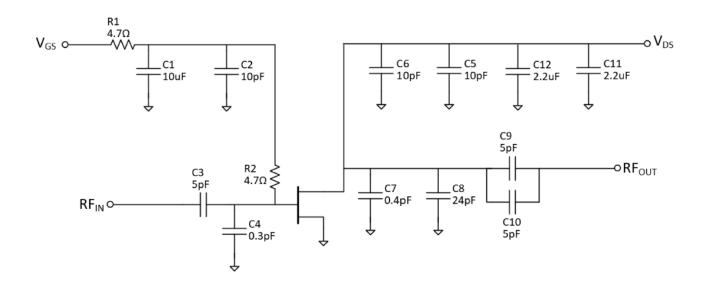


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### Evaluation Test Fixture and Recommended Tuning Solution 2.9 - 3.3 GHz



## **Description**

Parts measured on evaluation board (20 mil thick RO4350B). Matching is provided using a combintion of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

# Bias Sequencing\* Turning the device ON

- 1. Set V<sub>GS</sub> to pinch-off (V<sub>P</sub>).
- 2. Turn on V<sub>DS</sub> to nominal voltage (50 V).
- 3. Increase V<sub>GS</sub> until I<sub>DS</sub> current is reached.
- 4. Apply RF power to desired level.

#### **Turning the device OFF**

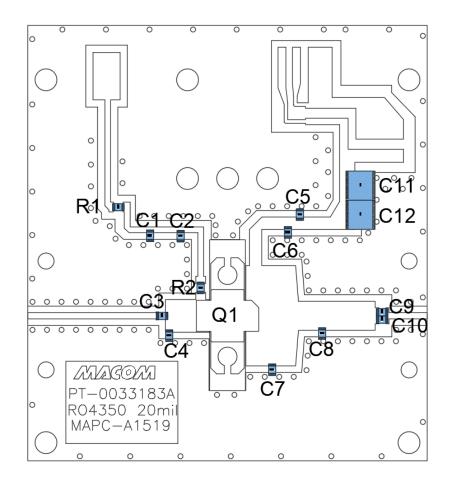
- 1. Turn the RF power OFF.
- 2. Decrease  $V_{\text{GS}}$  down to  $V_{\text{P}}$  pinch-off.
- 3. Decrease  $V_{DS}$  down to 0 V.
- 4. Turn off  $V_{\text{GS}}$ .

<sup>\*</sup> For an integrated power management solution please contact MACOM support regarding the MABC-11040.



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## Evaluation Test Fixture and Recommended Tuning Solution 2.9 - 3.3 GHz



Reference Designator	Value	Tolerance	Manufacturer	Part Number	
C1	10 μF	+/- 20%	TDK	C2012X5R1C106M085AC	
C2,C5,C6	10 pF	+/-1%	Murata	GQM1875C2E100FB12D	
C3,C9,C10	5 pF	+/- 0.1pF	Murata	GQM1875C2E5R0BB12D	
C4	0.3 pF	+/- 0.1pF	Murata	GQM1875C2ER30BB12D	
C7	0.4 pF	+/- 0.1pF	Murata	GQM1875C2ER40BB12D	
C8	24 pF	+/- 5%	ATC	800A240JT250X	
C11,C12	2.2 µF	+/- 20%	Murata	KRM55TR72E225MH01L	
R1,R2	4.7 Ω	+/- 5%	Yageo	RC1206JR-074R7L	
Q1	MACOM GaN Power Amplifier MAPC-A1			MAPC-A1519	
PCB	RO4350B, 20 mil, 1oz Cu, ENIG Finish				

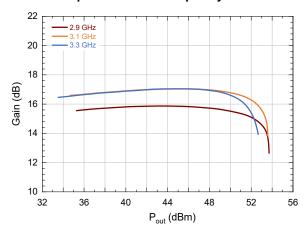
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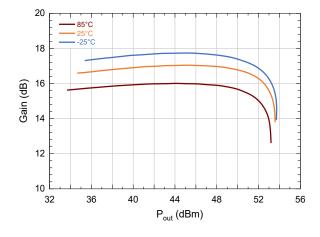
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Typical Performance Curves as Measured in the 2.9 - 3.3 GHz Evaluation Test Fixture: Pulsed<sup>2</sup> 3.1 GHz,  $V_{DS}$  = 50 V,  $I_{DO}$  = 300 mA,  $T_{C}$  = 25°C (Unless Otherwise Noted)

Gain vs. Output Power and Frequency

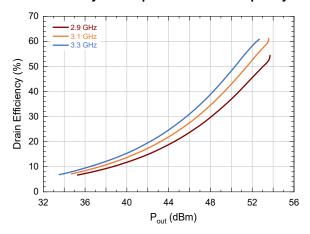


#### Gain vs. Output Power and Tc

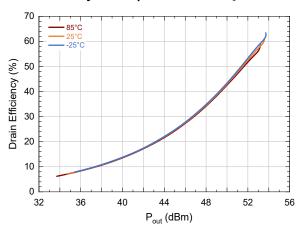


For further information and support please visit: <a href="https://www.macom.com/support">https://www.macom.com/support</a>

#### Drain Efficiency vs. Output Power and Frequency



#### Drain Efficiency vs. Output Power and T<sub>C</sub>



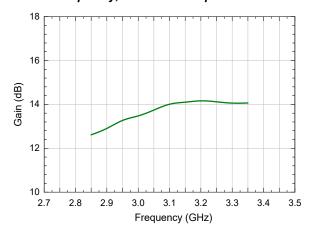


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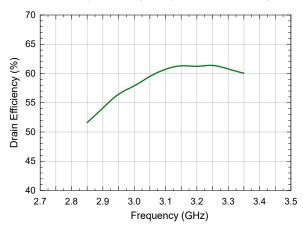
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Typical Performance Curves as Measured in the 2.9 - 3.3 GHz Evaluation Test Fixture: Pulsed<sup>2</sup> 3.1 GHz,  $V_{DS}$  = 50 V,  $I_{DO}$  = 300 mA,  $T_{C}$  = 25°C (Unless Otherwise Noted)

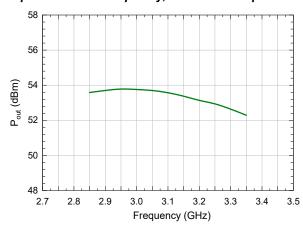
Gain vs. Frequency, 3dB Gain Compression



Drain Efficiency vs. Frequency, 3dB Gain Compression



Output Power vs. Frequency, 3dB Gain Compression



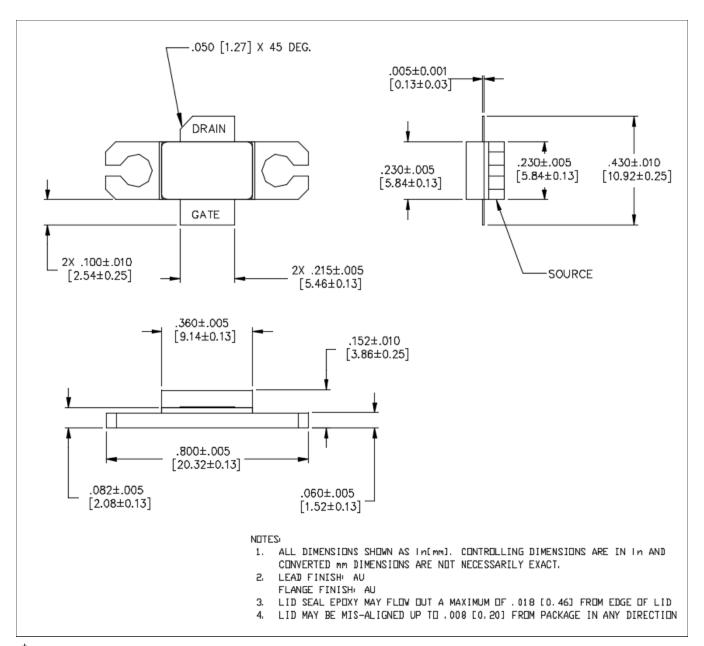
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## Lead-Free AC-360B-2 Package Dimensions<sup>†</sup>



<sup>&</sup>lt;sup>†</sup> Reference Application Note AN0004363 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Au.

## GaN Amplifier 50 V, 200 W

2.9 - 3.3 GHz



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